

Ferroic orders in two-dimensional transition/rare-earth metal halides

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ABSTRACT

Since the discovery of graphene, two-dimensional materials with atomic level thickness have rapidly grown to be a prosperous field of physical science with interdisciplinary interest for their fascinating properties and broad applications. Very recently, the experimental observation of ferromagnetism in a $\text{Cr}_2\text{Ge}_2\text{Te}_6$ bilayer and a CrI_3 monolayer opened a door to pursue long-absent intrinsic magnetic orders in two-dimensional materials. Meanwhile, the ferroelectricity was also experimentally found in a SnTe monolayer and CuInP_2S_6 few layers. The emergence of these ferroic orders in the two-dimensional limit not only brings new challenges to our physical knowledge but also provides more functionalities for potential applications. Among various two-dimensional ferroic ordered materials, transition/rare-earth metal halides and their derivants are very common. In this Research Update, based on transition/rare-earth metal halides, the physics of various ferroic orders in two-dimensional materials will be illustrated. The potential applications based on their magnetic and polar properties will also be discussed.

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I. INTRODUCTION

For rich low-dimensional physics and promising potential applications, the research enthusiasm on two-dimensional (2D) materials has been aroused since the successful exfoliation of graphene in 2004.¹ Thanks to the extensive efforts devoted to the field of 2D materials, great progress has been achieved in the past few decades. For example, numerous single-element monolayers have been discovered and synthesized, such as borophene, silicene, phosphorene, germanene, and antimonene. All these single-element monolayers are small gapped semiconductors but with relatively poor mechanical and electrical properties compared with graphene. Furthermore, monolayers with binary elements have also been found, such as hexagonal boron nitride (BN), molybdenum disulfide (MoS_2), and so on.

However, all these 2D pioneers are plain semiconductors or semi-metals, in which the charge is the dominant degree of freedom. Other functional properties such as magnetism and polarity originating from other degrees of freedom (e.g., spin, orbital, and lattice) are generally inactive or negligible in these systems, which limits their application regions. Although many *ab initio*

calculations and some delicate experiments claimed that the magnetism in 2D materials is induced by surface decorations, boundary edges, doping, defects, or biased electric field, these types of magnetism are somewhat extrinsic. Despite tremendous efforts, these types of extrinsic magnetism induced by external factors are still hindered by their weak magnetization, low working temperature, weak robustness, and uncontrollability.

In contrast, 2D intrinsic magnetic materials with spontaneous long-range spin orders and homogeneous stable magnetization are obviously more appealing, which is more important for spintronic devices in the nanoscale and even angstrom-scale. However, limited by the Mermin–Wagner theorem,² for spin systems with continuous rotational symmetry, e.g., the isotropic Heisenberg model or X–Y model, long-range magnetic orders in the 2D limit cannot be spontaneously stabilized at finite temperatures due to the thermal perturbation. Fortunately, this restriction can be avoided when any single-axis anisotropy exists, e.g., an easy axis of magnetocrystalline anisotropy or external magnetic field. For example, for standard 2D Ising spins on the square lattice, its ferromagnetic Curie temperature (T_C) is $\sim 2.27J$,³ where J is the exchange between nearest-neighbor spins. In addition, it should be noted that the Mermin–Wagner

theorem is derived under the conditions of the thermodynamic limit, which works for systems with infinite size. For finite size systems, the magnetic orders can be established once the magnetic correlation length is over the system size. Thus, the limit of the Mermin–Wagner theorem will not be a principal barrier for 2D magnetic ordering.^{4,5}

While for polar systems, discrete polar axes always exist naturally, without the continuous rotational symmetry, which is advantageous to avoid the restriction of the Mermin–Wagner theorem in the 2D limit.⁶ However, there is another obstructive factor in practice, i.e., the depolarization fields from surfaces and/or interfaces. The discontinuous polarization component perpendicular to the surfaces/interfaces can generate an electrostatic field, which is the main driving force of depolarization.⁷ In addition, the breaking crystalline symmetry and many dangling bonds may lead to polar surfaces/interfaces and serious surface/interfacial reconstructions, which can be another source of depolarization effect. Comparing with conventional three-dimensional (3D) crystals, these surface effects are much more serious in 2D sheets due to the super surface-to-volume ratio. Similar surface effects also exist in magnetic films, leading to the common “dead layer” in ultra-thin films.⁸

In principle, 2D magnetic/polar materials can be obtained by reducing the thickness of 3D crystals to the 2D limit, e.g., by growing ultra-thin films down to atomic level thickness using molecular beam epitaxy (MBE) or pulsed laser deposition.^{8,9} However, the open surfaces remain as a big challenge for alloys and oxides whose original 3D bonding networks are broken at surfaces.

In this sense, the van der Waals (vdW) magnetic/polar materials are highly valuable for the physics community and material community. According to the experience from past studies on 3D magnetic and polar systems, transitional metal elements or rare-earth elements seem to be essential to be involved as cations. In addition, there are more chances for halides than oxides to host these vdW magnets or polar systems since halogen ions prefer less chemical bond coordinates than oxygen. Less chemical bonds are advantageous to form passivated surfaces of vdW sheets. Thus, transition metal or rare-earth metal halides are rich ore for 2D ferroic orders, which is the topic of this Research Update.

Thanks to the rapid developments of materials synthesis and *in situ* measurements, remarkable progress has been made in this field.¹⁰ Due to the page limit and our knowledge limit, the aim of this Research Update is not to be a comprehensive encyclopedia of all 2D magnetic and polar halides but to clarify the main relevant physics based on selected examples since many materials share common physics.

This Research Update is organized as follows. First, Sec. II will describe the most representative CrX_3 family, which has been extensively studied in recent years. Second, Sec. III will review other 2D metal trihalide magnets, which share similar honeycomb lattice but are much less verified. Third, Sec. IV will give a brief introduction to some metal dihalides, which own the triangular lattice and, thus, different physics. The geometric frustration may play a vital role in these systems. Finally, several low-dimensional polar oxyhalides, with rectangular geometry, will be discussed. In some systems, both magnetism and polarization exist and are coupled mutually.

II. CHROMIUM TRIHALIDES

A. CrX_3 monolayer: 2D ferromagnets

The CrI_3 monolayer was one of the first two experimentally confirmed intrinsic 2D ferromagnetic materials,¹¹ and the other one was the $\text{Cr}_2\text{Ge}_2\text{Te}_6$ bilayer.¹² Following this breakthrough, enormous efforts have been devoted to CrI_3 , its derivatives, and its sister compounds. Prototype devices based on the CrI_3 monolayer or few layers have also been designed and fabricated to demonstrate the spintronic functions for applications.

CrX_3 ($X = \text{Cl}, \text{Br}, \text{and I}$) bulks share the identical in-plane symmetry. As shown in Figs. 1(a) and 1(b), each Cr^{3+} is caged in a halogen octahedron, and neighboring octahedra connect in the edge-sharing manner, forming the hexagonal honeycomb lattice. Upon cooling, there is a structural transition from monoclinic ($C2/m$, AlCl_3 structure) to rhombohedral ($R\bar{3}$, BiI_3 structure) corresponding to the interlayer stacking sliding, which occurs at about 240 K/420 K/210 K–220 K for $X = \text{Cl}/\text{Br}/\text{I}$, respectively.^{13,14}

Actually, as early as in the 1960s, unambiguous in-plane ferromagnetism [Fig. 1(c)] was confirmed in CrX_3 crystals whose magnetic transition temperatures are around 17/37/61(8) K for $X = \text{Cl}/\text{Br}/\text{I}$, respectively.^{14–16} This increasing trend can be attributed to two reasons:¹⁷ first, the net ferromagnetic exchanges (in fact, a cooperative effect from various competitive exchanges) weaken when the lattices shrink; second, the spin–orbit coupling increases with the atomic number, which enhances the magnetic anisotropy, an essential factor for long-range magnetic ordering in low-dimensions. Furthermore, a recent experimental study on the CrI_3 crystal revealed a strong Kitaev interaction between spins, which is also responsible for higher T_C .¹⁸ The magnetic moments of Cr in all cases are close to the expected $3\mu_B$.¹⁴ The interlayer coupling is ferromagnetic for $X = \text{Br}$ and I ¹⁴ but antiferromagnetic for $X = \text{Cl}$.¹⁹ The magnetocrystalline anisotropy is also different between

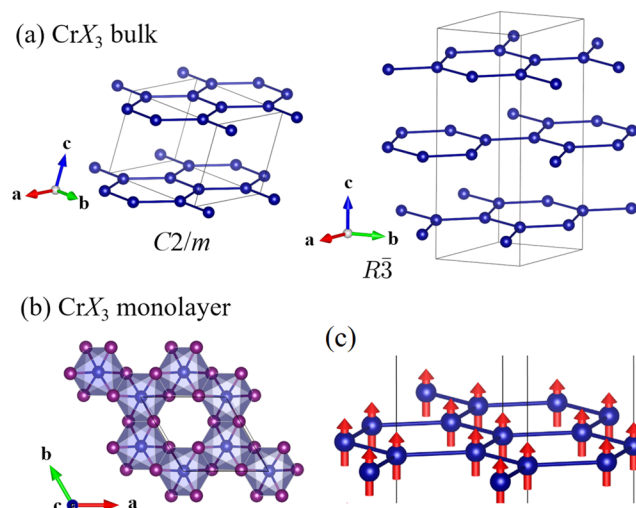


FIG. 1. (a) Schematic structure of the CrX_3 bulk. The left panel shows the high-temperature one, and the right panel shows the low-temperature one. Only Cr ions are shown for simplicity, which form the honeycomb structure. (b) Top view of the CrX_3 monolayer. (c) Side view of ferromagnetic spin order on Cr sites.

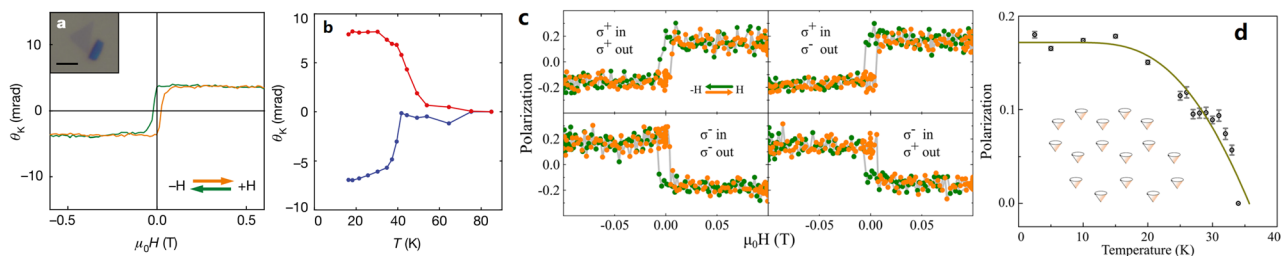


FIG. 2. (a) MOKE signal of the CrI_3 monolayer at 15 K as a function of the magnetic field. The ferromagnetic hysteresis loop is observed. (b) MOKE signal of the CrI_3 monolayer as a function of temperature. Blue indicates zero-field cooling. Red indicates field cooling at 0.15 T. (c) Polarization resolved magneto-photoluminescence for the CrBr_3 monolayer. σ^+ (σ^-) denotes the left (right) circularly polarized light. Ferromagnetic hysteresis loops are observed. (d) The signal of the CrBr_3 monolayer as a function of temperature, suggesting a T_C at ~ 34 K. [(a) and (b)] Reprinted with permission from Huang *et al.*, *Nature* **546**, 270 (2017). Copyright 2017 Springer Nature. [(c) and (d)] Reprinted with permission from Zhang *et al.*, *Nano Lett.* **19**, 3138 (2019). Copyright 2019 American Chemical Society.

$\text{CrBr}_3/\text{CrI}_3$ and CrCl_3 . In short, CrBr_3 and CrI_3 are similar layered ferromagnets with spins pointing out-of-plane, but CrCl_3 is a unique layered antiferromagnet with spins lying in plane.^{14,19}

Based on the first-principles calculations, the estimated cleavage energies indicate the easy preparation of monolayers for all CrX_3 's.^{14,17} The stability of their free-standing monolayers was further confirmed by elastic property calculations and molecular dynamics simulations. The ferromagnetism was predicted to persevere down to monolayers for all CrX_3 's, due to the robust intralayer ferromagnetic Cr- X_2 -Cr super-exchange.¹⁷

The experimental confirmation was delayed by technical difficulties in high-quality sample preparation and high-precision detection. Until 2017, Huang *et al.* successfully obtained the CrI_3 monolayer by mechanical exfoliation.¹¹ As illustrated in Fig. 2(a), the spontaneous magnetization with out-of-plane orientation was observed in the CrI_3 monolayer by magneto-optical Kerr effect (MOKE) microscopy, which is a powerful tool to monitor the tiny ferromagnetism signal in 2D sheets. T_C of the CrI_3 monolayer is 45 K [Fig. 2(b)],¹¹ lower than its bulk value.

Very recently, the intrinsic ferromagnetism in the CrBr_3 monolayer was also evidenced [Fig. 2(c)].^{20,21} The measured T_C of the CrBr_3 monolayer was 34 K [Fig. 2(d)],²⁰ slightly lower than its bulk value. Stable CrCl_3 few layers and monolayer were also successfully cleaved from the crystal, although their magnetism need further direct experimental verification.^{22,23}

Despite the similarity, CrBr_3 is more stable in air than CrI_3 .^{11,24} In fact, CrI_3 flakes are easy to be decomposed under an ambient condition and have to be protected under an inert atmosphere, while CrBr_3 samples have much longer lifetime in air and do not require special protection. Thus, CrBr_3 may provide a better platform to research 2D magnetism and their applications.

B. CrX_3 few layers: Antiferromagnetism vs ferromagnetism

More interestingly, the CrI_3 bilayer exhibits an unexpected antiferromagnetic interlayer coupling,¹¹ although its bulk is ferromagnetic. This antiferromagnetic interaction across the vdW gap is naturally fragile, which can be tuned by strain and stacking modes between layers. The antiferromagnetic bilayer was argued to stack in the manner of high-temperature one (i.e., $C2/m$, AlCl_3

structure), while the low-temperature stacking manner remains ferromagnetic.^{25–28}

When the layer number is further increased, the ferromagnetic state will be recovered and its T_C will restore to the bulk value,¹¹ although the following work argued a ferrimagnetic state, i.e., antiferromagnetic coupling between layers.²⁹ This layer-dependent magnetic behavior greatly promoted the investigation of quantum magnetic phenomena and the development of spintronic devices.

In contrast, the interlayer coupling in the CrBr_3 bilayer was determined to be ferromagnetic.²⁰ However, the stacking-dependent interlayer coupling was also proposed for the CrBr_3 bilayer.²¹ In detail, using MBE, Chen *et al.* successfully prepared the CrBr_3 monolayer and bilayer with two distinct stacking patterns (defined as H- and R-types). According to the hysteresis loops, the H-type bilayer prefers ferromagnetic interlayer coupling, while in the R-type sample, the two layers are antiferromagnetically coupled. This phenomenon was somewhat similar (although not identical) to the situation of the CrI_3 bilayer, providing a feasible new way to control magnetism in bilayers.

As a unique member, the layered antiferromagnetism in CrCl_3 can persist to the bilayer,²³ while its stacking dependence has not been explored yet.

The antiferromagnetic CrI_3 bilayer can be easily driven to ferromagnetic via a meta-magnetic transition, with the critical magnetic field of about 0.6 T–0.8 T, as depicted in Figs. 3(b) and 3(e).^{11,29–31}

Such layered antiferromagnetism can be implemented in magnetoresistance devices, which is of great importance in information processing and data storage. Indeed, giant tunneling magnetoresistance in vdW heterostructures has been demonstrated with CrI_3 or CrCl_3 bilayers/trilayers acting as a spin-filter barrier, as shown in Figs. 3(a) and 3(b).^{23,29,32} In addition, the related microscopic mechanism of spin-filtering has been clarified.³³ In turn, Klein *et al.* utilized the tunnel conductance to probe the magnetic ground state and interlayer coupling.³⁴ Moreover, by combining the magnetoelectric effect and the spin-filter effect, Jiang *et al.* designed a spin tunnel field-effect transistor (FET) based on the CrI_3 vdW heterostructure.³⁵ Soon after, the on-off ratio of the CrI_3 FET was successfully promoted up to 10^4 .³⁶ Additionally, many other interesting phenomena, such as magneto-optical effect and spin-valley effect, have also been investigated in CrI_3 sheets.^{37–39}

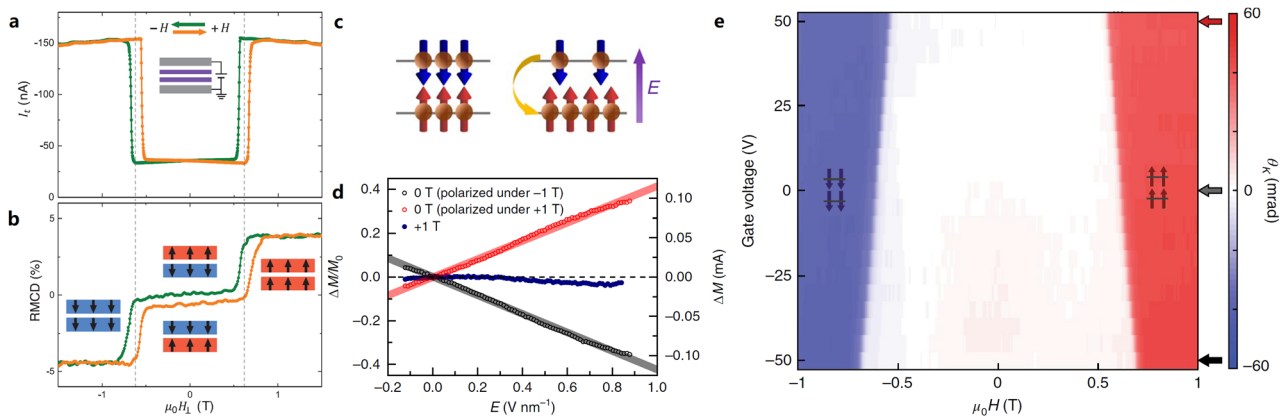


FIG. 3. Physical properties and functionalities of the CrI₃ bilayer. (a) Giant tunneling magnetoresistance, which corresponds to (b) the meta-magnetic transition. [(c) and (b)] Linear converse magnetoelectric effect. (c) Schematic of the physical mechanism: the electric field can tune the charge distribution between two layers. (d) Experimental result of electric field induced magnetization, which depends on the history of the poling magnetic field. (e) Phase diagram characterized by the MOKE signal as a function of electric and magnetic fields. Around the phase boundary between the ferromagnetic and antiferromagnetic states, the electric field can tune the meta-magnetic phase transition. [(a) and (b)] Reprinted with permission from Song *et al.*, *Science* **360**, 1214 (2018). Copyright 2018 American Association for the Advancement of Science. [(c) and (d)] Reprinted with permission from Jiang *et al.*, *Nat. Mater.* **17**, 406 (2018). Copyright 2018 Springer Nature. (e) Reprinted with permission from Huang *et al.*, *Nat. Nanotechnol.* **13**, 544 (2018). Copyright 2018 Springer Nature.

Besides these functionalities controlled by the magnetic field, the converse magnetoelectric effect, i.e., to control magnetism using the electric field, has also been demonstrated in the CrI₃ bilayer, as shown in Figs. 3(c)–3(e).^{30,31} Two mechanisms were involved. First, upon the applied electric field, the electrostatic potential between two layers leads to uncompensated spin moments [Figs. 3(c) and 3(d)], i.e., a pure electrostatic effect for layered antiferromagnetism, and thus, the linear magnetoelectric effect occurs. Second, near the vicinity of the interlayer spin-flip transition, the CrI₃ bilayer can be switched between antiferromagnetism and ferromagnetism by the electric field with the help of the biased magnetic field, as shown in Fig. 3(e).

Such electric field induced meta-magnetic transition in the CrI₃ bilayer was explained based on density functional theory (DFT) and tight-binding model calculations.⁴⁰ Later, Jiang *et al.* revealed that the electrostatic doping in CrI₃–graphene vertical heterostructures can tune the magnetism of both the CrI₃ monolayer and the bilayer, even without the biased magnetic field.⁴¹ These results paved the way to pursuit voltage manipulation of the spin state in the 2D limit.

C. Modification of physical properties

Besides these experimental attempts to utilize CrX₃ monolayers and few layers, other modulations of CrX₃ sheets have also been theoretically predicted. For example, to promote the ferromagnetic T_C , Huang *et al.* suggested an isovalent alloying method, which could enhance T_C of the CrWI₆ monolayer by three to five times comparing with pristine CrI₃.⁴²

In addition, the strain and charge doping effects have also been revealed, exhibiting a rich magnetic phase diagram and evoking further experimental verifications.⁴³ For example, phase

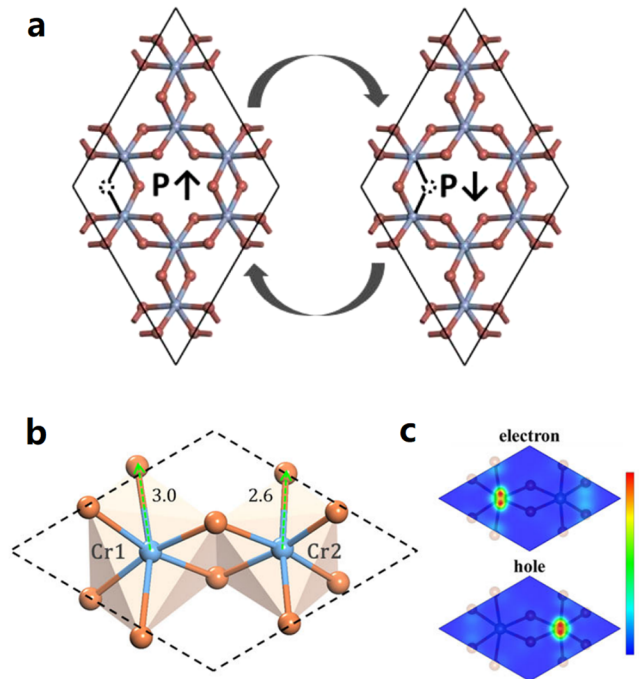


FIG. 4. Generating electric dipoles in CrX₃ monolayers. (a) Out-of-plane polarization induced by an iodine vacancy. [(b) and (c)] Unequal Jahn–Teller distortion and charge density at neighbor Cr sites in the half-doped CrBr₃ monolayer, which can generate in-plane polarization. (a) Reprinted with permission from Zhao *et al.*, *Nano Lett.* **18**, 2943 (2018). Copyright 2018 American Chemical Society. [(b) and (c)] Reprinted with permission from Huang *et al.*, *Phys. Rev. Lett.* **120**, 147601 (2018). Copyright 2018 American Physical Society.

transition from the ferromagnetic state to antiferromagnetic one will occur when these trihalide monolayers are compressively strained.⁴⁴ Contrarily, a moderate tensile strain will strengthen ferromagnetic coupling and enhance both magnetic anisotropy and transition temperatures of CrCl_3 and CrBr_3 .⁴⁴

Moreover, Zhao *et al.* demonstrated that surface I vacancies of the CrI_3 monolayer can enhance the local magnetic moment and increase T_C .⁴⁵ More intriguingly, the surface vacancy can induce an out-of-plane polarization, as sketched in Fig. 4(a).⁴⁵ The coexistence of stable ferromagnetism and switchable polarization makes the $\text{CrI}_{3-\delta}$ monolayer a magnetoelectric material. The point defect can even induce magnetic phase transition at certain concentration.⁴⁶

Theoretically, Huang *et al.* predicted 2D ferromagnetic ferroelectricity in the charged CrBr_3 layer.⁴⁷ Based on DFT calculations, they demonstrated that electron doping would induce unequal spatial electron-hole distribution on two Cr sites within a CrBr_3 primitive cell [Fig. 4(c)]. As a result of the charge ordering behavior, asymmetric Jahn-Teller distortion spontaneously takes place in two neighboring Cr- Br_6 octahedra [Fig. 4(b)] and thus leads to orbital ordering. Due to the combination of charge ordering and orbital ordering, the pristine D_{3d} symmetry is broken and replaced by the polar C_2 symmetry; meanwhile, the in-plane polarization emerges.

The possibility of magnetoelectric coupling was further proved by magnetization modulation with the electric field.

All the above theoretical predictions are valuable guides for experimental discoveries.

III. OTHER MX_3 : CONTROVERSIES TO BE VERIFIED

Encouraged by the great progress of the CrX_3 family, it is natural to look at other MX_3 's, where M can be V, Ni, Fe, Mn, and Ru.

Different from the widely studied CrX_3 , the studies on vanadium trihalides (VX_3) are quite rare. In the 1980s, bulk VI_3 was first reported as a layered ferromagnetic insulator with T_C around 55 K,⁴⁸ which was confirmed by recent magnetization measurements (50 K).⁴⁹ Its effective moment was about $2 \mu_B$ per vanadium. Besides, the magnetic anisotropy was also observed with the easy axis normal to VI_3 sheets.^{50,51} The insulating bandgap of 0.67 eV was determined by electrical and optical transport measurements.⁵⁰

Its structural space group was reported to be $R\bar{3}$ below 80 K,⁴⁹ identical to CrI_3 . However, Son *et al.* showed that its low-temperature structure determined by refined powder x-ray diffraction was in better agreement with monoclinic $C2/c$ symmetry.⁵¹

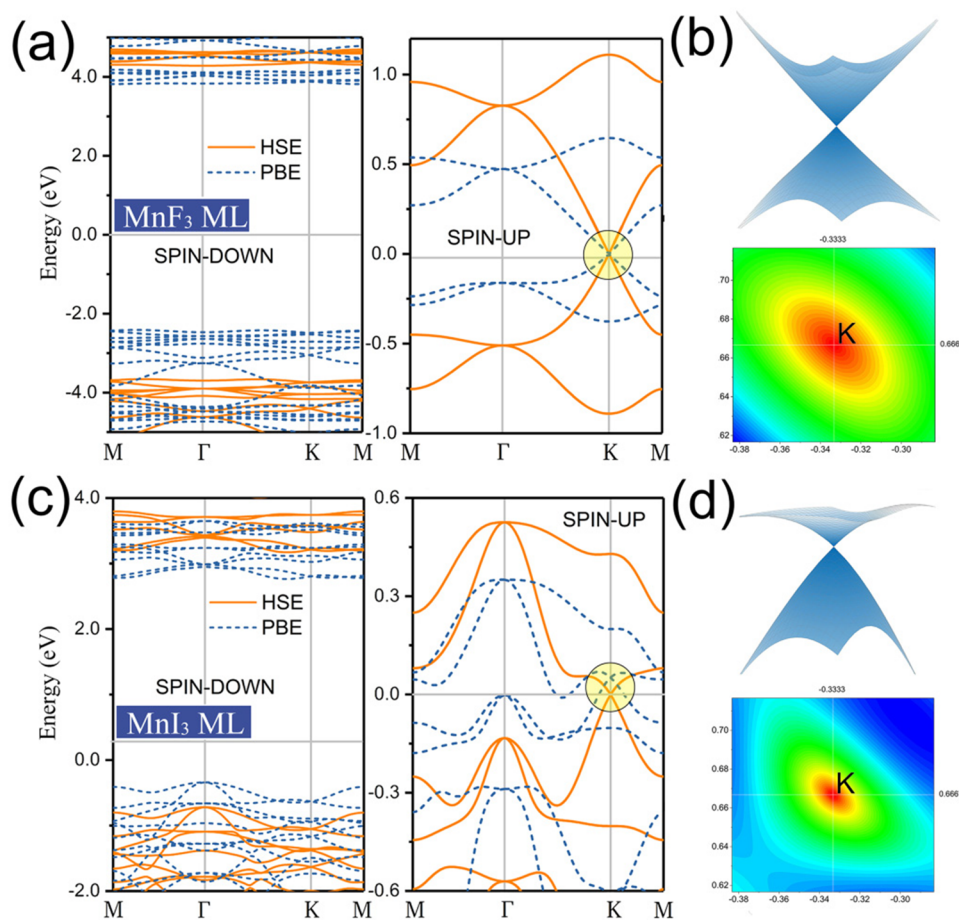


FIG. 5. Dirac half-metal characteristic of MnX_3 monolayers. [(a) and (c)] DFT band structure of the ferromagnetic MnF_3 and MnI_3 monolayers, respectively. [(b) and (d)] 3D band structure of the Dirac cone and its projection on the Brillouin zone. Reprinted with permission from Q. Sun and N. Kioussis, Phys. Rev. B **97**, 094408 (2018). Copyright 2018 American Physical Society.

which was then confirmed by An *et al.* through the first-principles calculation.⁵² Furthermore, Doležal *et al.* claimed another structural phase transition to triclinic upon further cooling down to 32 K. Thus, further studies are necessary to clarify its ground state structure.⁵³

Despite the dispute of its bulk structure, the easy cleavable nature of VI_3 has been confirmed both theoretically and experimentally.^{49,51,52,54} Based on DFT calculations, the ferromagnetic order can persist to the monolayer.⁵² The estimated T_C of the monolayer is about 27 K,⁵² almost half of its bulk value. Such a reduction in T_C was attributed to the reduced magnetic interaction due to the in-plane lattice expansion.⁵² Some works claimed the change in magnetic anisotropy, i.e., from the easy axis off-plane in the bulk to the easy xy plane in the monolayer,⁵² while some claimed unchanged.^{55,56} More serious disagreement regarding the monolayer is that some work claimed a Dirac half-metal,⁵⁴ while some predicted an insulator in agreement with its bulk.⁵²

The close relationship between the stacking pattern and the interlayer magnetic coupling was also predicted in the bilayer VI_3 ,⁵⁵ i.e., the ground state stacking order (AB stacking) prefers the ferromagnetic coupling, while the meta-stable one (AB' stacking) prefers the antiferromagnetic coupling.

As the sister members of VI_3 , VCl_3 and VBr_3 are naturally expected to be promising 2D magnetic systems. Theoretical studies have been done to examine the magnetic properties of the VCl_3 monolayer.^{54,57} Although the consistent conclusion of the ferromagnetic ground state was reached, there was serious inconsistency regarding its T_C , i.e., 80 K predicted by He *et al.* but over 400 K by Zhou *et al.*^{54,57}

Further works, especially more precise experimental works, are highly desired to verify the above inconsistent predictions on VX_3 sheets.

Besides VX_3 , MnX_3 is also a promising candidate family. Based on DFT calculations, Sun *et al.* predicted that 2D stable hexagonal MnX_3 monolayers possess large magnetic moment ($4 \mu_B/\text{Mn}$), in-plane magnetic anisotropy, high T_C above room temperature (450 K–720 K), and ideal Dirac half-metal characteristic (Fig. 5).⁵⁸ Such high T_C must be overestimated considering the Ising model used. Similar to VX_3 , both the magnetic moment and the estimated transition temperature exhibit an increasing tendency with the atomic number of the halogen ion in MnX_3 .⁵⁸

Nickel trihalides were predicted to be another candidate family with an ideal Dirac half-metal nature and intrinsic 2D ferromagnetism above the room temperature.⁵⁹ The estimated magnetic moment was about $1 \mu_B$ per Ni^{3+} , consistent with its low spin configuration. Similar trend of magnetic enhancement was observed in NiX_3 from Cl to I. The experimental feasibility of NiX_3 monolayers was proved by the stability analysis up to 500 K.

For iron trihalides, the magnetism is not plain ferromagnetic. Early works reported the peculiar in-plane helimagnetic structure.^{19,60} Antiferromagnetic stacking was observed in FeCl_3 and FeBr_3 below 10 K and 16 K.^{19,60}

Besides these binary element MX_3 , some combinations of $\text{MM}'\text{X}_6$ have also been calculated, which suggests more magnetic candidates to be tuned.⁵²

The transition metal in MX_3 can also be heavier 4d ones, which own a weaker Hubbard correlation but stronger spin–orbit coupling

than 3d elements. More novel physical properties can be expected in these 4d trihalides. For example, $\alpha\text{-RuCl}_3$ was supposed to be a model system for Kitaev interaction and a candidate of quantum spin liquid. However, complex low-temperature structure and multiple magnetic phase transitions were detected in $\alpha\text{-RuCl}_3$, which might be related to the symmetry difference caused by different stacking modes.^{61,62} The only information available was its in-plane zig-zag antiferromagnetic state, with an interlayer antiferromagnetic stacking order.⁶³ The magnetic moments, including both the

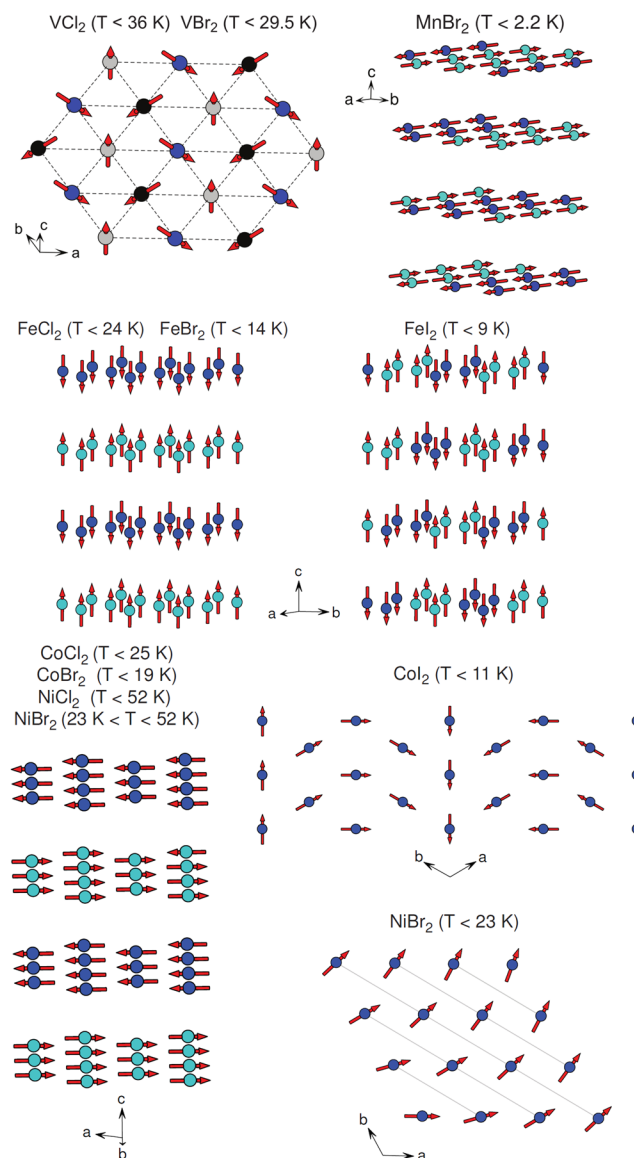


FIG. 6. Schematic of various magnetic orders in MX_2 bulks. The corresponding orders in monolayers of few layers have not been experimental verified but promisingly interesting. For those noncollinear spin orders, ferroelectric polarization may be generated. Reprinted with permission from M. McGuire, Crystals 7, 121 (2017). Copyright 2017 McGuire.

spin and orbit components, were reported to have both in- and off-plane components, which further complicates the magnetic structure in α -RuCl₃.⁶⁴ The knowledge of magnetic nature of the 2D α -RuCl₃ monolayer or few layers remains very limited.

In short, other MX_3 families beyond Cr trihalides can host exotic magnetism, but the studies remain far from completed. Many theoretical predictions are full of uncertainty. Further careful calculations and experimental investigations are urgently needed.

IV. MX_2 : TRIANGULAR MAGNETS

Besides trihalides, metal dihalides are also available as vdW magnetic materials. The key physics for these compounds is their 2D triangular lattice, which is geometrically frustrated for antiferromagnets.

The MX_2 bulks also have two types of stacking modes: the trigonal CdI₂ type (AA stacking) and the rhombohedral CdCl₂ one (ABC stacking). Structural transition between these two types is also possible upon the change in temperature and pressure. Within each layer, each M ion is also caged in an X -octahedron, and these octahedra connect with neighbors in the edge-sharing mode.

Most known MX_2 bulks are antiferromagnetic, although some of them are ferromagnetic within each layer.⁶⁵ Some typical magnetic textures are summarized in Fig. 6 by McGuire. The net exchanges within each layer may be complex, due to the multiple origins of exchanges. In particular, MX_2 ($M = \text{Fe, Co, X} = \text{Cl, Br}$) are ferromagnetic within each layer at low temperatures, but neighboring layers are antiferromagnetically coupled. However, their sister member FeI₂ is stripy antiferromagnetic in a layer, while CoI₂ owns the spiral antiferromagnetism as a ground state. More complexly, NiBr₂ is ferromagnetic in a layer in a middle temperature region (from 23 K to 52 K) but changes to a long period helimagnetic structure below 23 K. The magnetic transition temperatures of most MX_2 series decrease with the atom number of X , in opposite to the general tendency in most MX_3 .¹⁴

For $M = \text{V}$ and Mn , antiferromagnetic coupling is expected within each layer, considering their d^3 and d^5 electron occupation (i.e., half-filling t_{2g} orbitals or $3d$ orbitals). Then, the geometrical frustration is unavoidable, which will reduce the ordering temperatures and generate noncollinear spin texture. The 120° Y-type

antiferromagnetism was reported for VCl₂ and VBr₂, as a typical result of geometrically frustration. More complicated helical magnetic structures were reported for VI₂, MnCl₂, and MnI₂, while MnBr₂ owns a stripy antiferromagnetism.

The noncollinear magnetic textures in these triangular lattices may break the spatial inversion symmetry and induce a ferroelectric polarization.^{66,67} In fact, for MnI₂, CoI₂, NiBr₂, and NiI₂ crystals, their magnetism-driven ferroelectricity has been experimentally known for a long time,^{68,69} which has also been explained.⁷⁰ In fact, the relationship between 120° Y-type antiferromagnetism and its ferroelectric polarization is a general physical phenomenon in 2D triangular magnets, including the fluoridized MXene monolayer.⁷¹

The monolayers of MX_2 have also been investigated theoretically. FeX₂, NiX₂ ($X = \text{Cl, Br, I}$), CoCl₂, and CoBr₂ monolayers were predicted to be ferromagnetic, while VX₂, CrX₂, MnX₂, and CoI₂ were predicted to be antiferromagnetic.^{72–75} It should be noted that in some of these theoretical studies, sometimes only simple antiferromagnetic textures were considered. Therefore, the real magnetic orders might be missed, and thus, more careful studies are necessary. For example, a recent study predicted complex skyrmionic lattices in the NiI₂ monolayer.⁷⁶

Another interesting MX_2 system is GdI₂, which contains $4f$ magnetic moment and owns the MoS₂-type structure. The $4f$ electrons can contribute a larger magnetic moment up to $7 \mu_B$ and relative larger magnetic anisotropy. The residual one $5d$ electron, playing as the intermediary, can align these $4f$ moments parallelly, persisting to the monolayer limit.⁷⁷

The experimental investigations on MX_2 monolayers or few layers are not as plenty as MX_3 , which call for more attention in near future. Till now, only FeCl₂ and NiI₂ on substrates were reported,^{78–80} although their magnetism has not been characterized.

V. OXYHALIDES: RECTANGULAR LATTICE FOR POLARITY

As the counterpart of magnetism, polarity in solids is also highly valuable. In 2D materials, the first experimentally discovered polar materials were the SnTe monolayer with in-plane polarization and CuInP₂S₆ few layers with out-of-plane polarization.^{81,82} Several exotic physical properties have been revealed, including the

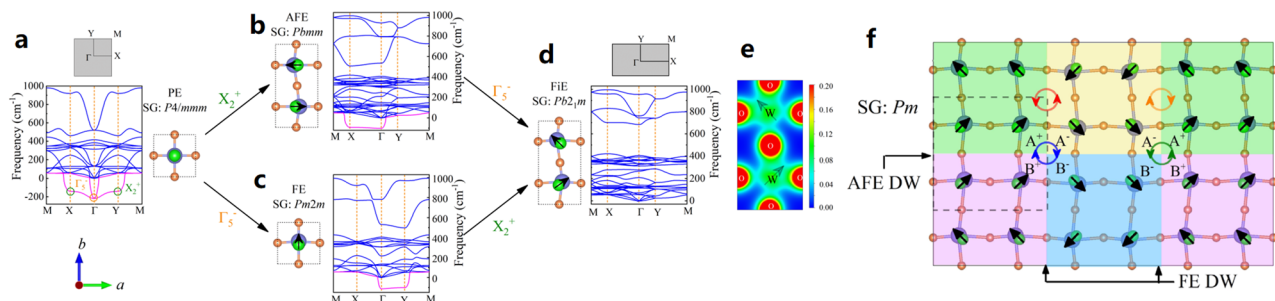


FIG. 7. Noncollinear ferroelectricity in WO_2Cl_2 . The phonon spectra of paraelectric (a), antiferroelectric (b), ferroelectric (e), and ferroelectric (d) states. (e) The d^0 rule-driven polarity. (f) The $\mathbb{Z}_2 \times \mathbb{Z}_2$ domain wall structures. Here, the domains (A^+ , A^- , B^+ , B^-) are characterized by their ferroelectric and antiferroelectric phases. The atomic level dipole vortices/antivortices (red and orange circles) are formed at the ferroelectric domain boundary. The antiphase domain vortices/antivortices are denoted by blue and green circles. Reprinted with permission from Lin *et al.* Phys. Rev. Lett. **123**, 067601 (2019). Copyright 2019 American Physical Society.

rare negative piezoelectricity.⁸³ More details of novel physics and its potential applications of CuInP_2S_6 can be found in a recent review.⁸⁴

As pointed out in the beginning, the less bonding characteristic of halogens is helpful to obtain the vdW gap and passivated surface. However, it seems that halogens do not prefer the polarity, at least for the proper polarity. However, in some vdW oxyhalides, the polarity can be obtained with the help of oxygen. Metal oxyhalides, in which anions include both oxygen and halogens, provide another low-dimensional platform with ferroic orders. These oxyhalides usually own rectangular lattice, instead of honeycomb and triangular ones.

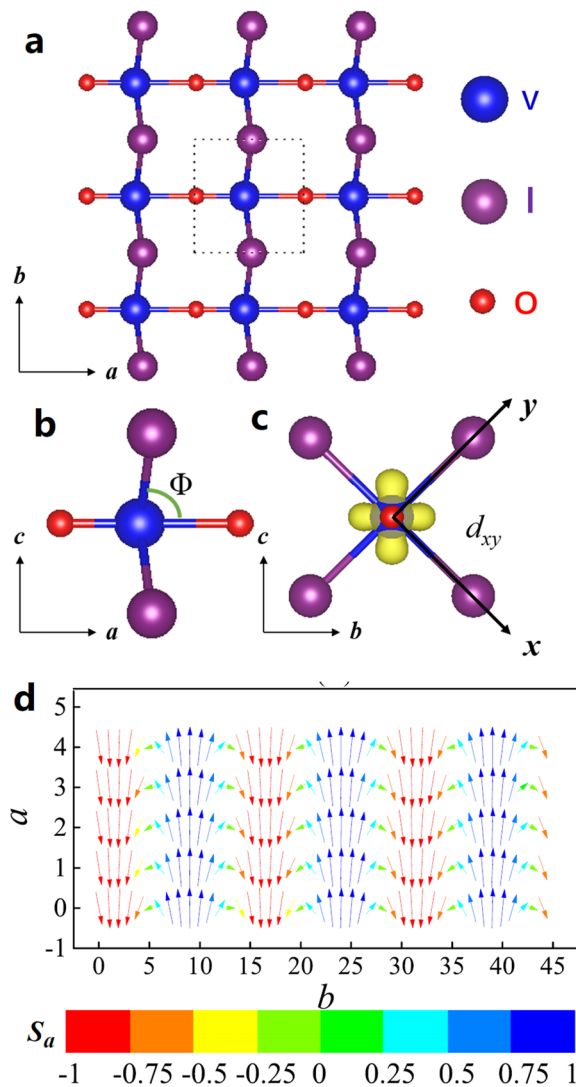


FIG. 8. Multiferroicity of VOI_2 . [(a)–(c)] Schematic structure of VOI_2 . (a) Top view. (b) Side view of a unit cell. (c) Side view from another side. The d^1 orbital shape is shown. (d) Possible magnetic ground state. A spiral spin order is induced by the strong Dzyaloshinskii–Moriya interaction associated with the polar distortion. Reprinted with permission from Ding *et al.*, Phys. Rev. B **102**, 165129 (2020). Copyright 2020 American Physical Society.

The pristine MO_3 crystal owns a perovskite-like framework, in which MO_6 octahedra connect with each other via corner sharing oxygen ions. By replacing one divalent oxygen with two monovalent halogen ions, the M–O–M chemical bonds between two adjacent layers will be cut off and replaced by a vdW gap. Based on this “scissors” effect, the three-dimensional MO_3 can be cut into 2D MO_2X_2 sheets,⁸⁵ and even one-dimensional (1D) MOX_4 chains,⁸⁶ or even to zero-dimensional (0D) MX_6 molecules.

WO_2Cl_2 and MoO_2Br_2 monolayers are representative materials of these 2D dioxydihalide families. Noncollinear polarity was predicted by Lin *et al.* through the phonon spectrum analysis. As shown in Figs. 7(a)–7(c), there are two polar phonon modes: one ferroelectric and one antiferroelectric. The combination of these two modes leads to the novel noncollinear ferrielectric texture, as shown in Figs. 7(d) and 7(e).

The polar distortions are driven by the d^0 rule and could hopefully strive up to room temperature.⁸⁵ In addition, more interestingly, such exotic noncollinear ferrielectric order can lead to novel physics such as a unique dipole vortex at the atomic level, topological $\mathbb{Z}_2 \times \mathbb{Z}_2$ domain antiphase vortex [Fig. 7(f)], and negative piezoelectricity.⁸⁵

Another concerned oxyhalide family is the VOX_2 monolayer, as shown in Figs. 8(a) and 8(b). All VOX_2 monolayers were predicted to be ferroelectric and magnetic, i.e., multiferroics.^{87,88} In particular, VOI_2 was predicted to be a rare ferromagnetic ferroelectric system.⁸⁷ The ferroelectricity originates from the orbital ordering of d^1 configuration [Figs. 8(b) and 8(c)], which mimics the d^0 rule in the V–O–V bond direction.⁸⁹ The magnetic moment from V^{4+} is $1 \mu_B$. However, due to the strong spin–orbit coupling of iodine, a strong Dzyaloshinskii–Moriya interaction is expected for the V–I₂–V bond, which is a side effect of ferroelectric polarization. Such Dzyaloshinskii–Moriya interaction will distort the magnetic texture to a spiral one [Fig. 8(d)], instead of a collinear ferromagnetic state.^{89,90} Thus, the prediction of the ferromagnetic ferroelectric ground state may be unavailable for VOI_2 . Instead, another end member VOF_2 may provide the possibility to obtain ferromagnetic plus ferroelectric properties since its spin–orbit coupling is much weaker.⁹¹

In short, the oxyhalide families provide opportunities for both magnetism and polarity in the 2D form. More experiments are encouraged in this direction.

VI. SUMMARY AND PERSPECTIVE

Obviously, the current research interest in low-dimensional functional materials is burgeoning. In this Research Update, the present status of some 2D vdW transition/rare-earth metal halides with intrinsic magnetism and polarity has been briefly summarized. Three selected categories have been presented: (1) MX_3 with honeycomb lattice, (2) MX_2 with triangular lattice, and (3) MO_2X_2 and MOX_2 with rectangular lattice. Most of these systems are magnetic, some are polar, and a few of them are multiferroics. Several physical mechanisms are involved, including magnetic exchanges, geometric frustration, topological bands and domain structures, and phonon instability.

The theoretical efforts, mostly based on the DFT calculations, have predicted many interesting candidates and desired properties, while the experimental decisive investigations remain challenging

due to the technical difficulties in the atomic scale. However, the theoretical calculations need to be more cautious, considering the subtle energies involved for vdW interactions, exchanges, anisotropy, dipole interactions, and spin-orbit coupling. All these interactions are “weak” in the energy scale of meV or even μeV . Approximation and imprecision in calculations may lead to controversial results, like what happened in many MX_3 's except CrX_3 . In experiments, the substrate effects, imperfectness of samples, surface absorptions (i.e., atmosphere and humidity), and other extrinsic issues may be much stronger in the energy scale and, thus, disturb the intrinsic ferroic properties.

Despite the great achievements in the past few years, there are more unknown issues or uncertainty in this emerging field. The following open questions are from our personal opinion.

Currently, the halogens involved in most of known 2D halides are Cl, Br, and I. However, the electronegativity of all these three elements is poor than that of oxygen. Thus, the chemical stability of these halides is mostly poor in air and against humidity, which is not good for real applications. Oxygen and hydroxyl can replace these halogens easily, leading to the decomposition of these materials. This problem is most serious for those iodides. Then, a natural expectation is whether fluorides can form these 2D halides. Theoretical calculations can be done easily for $\text{MF}_2/\text{MF}_3/\text{MO}_n\text{F}_2$. However, many corresponding fluorides are not vdW materials but 3D ionic crystals due to the very small size of the fluorine ion. Are these 2D fluorides hopeless or promising?

In many 3D ionic crystals, e.g., ABO_3 perovskites, there are two cation sites. Doping on the A site can largely tune the electron density at the B site but can keep the structure unbroken. Thus, the physical properties can be tuned continuously. However, in aforementioned halides, typically only one cation site is involved. The passivated surface of 2D halides and sole cation site makes the electron density tuning at the M site difficult. Although electrostatic effect and surface absorptions/defects can do this job, they are not the robust routes for applications. Then, how to effectively tune the electron density in the cation site?

Most physical properties of 2D halides reviewed above are inherited from their vdW bulks. In most cases, the ordering temperatures are reduced comparing with their corresponding bulks. Although some theoretical calculations predicted high ordering temperatures in some systems, none of them has been really confirmed experimentally yet. Is it possible for these 2D ferroic materials to have improved performances or even emergent new properties beyond bulks?

Most magnetic textures revealed in these 2D magnets are simple ones, although some noncollinear helical ones exist in these corresponding bulks or in DFT predictions. Recently, more complex skyrmions have been predicted and demonstrated in the 2D limit,^{76,92–95} which certainly deserve more careful studies.

Besides, the emergent physics of moiré structures in the twisted 2D bilayer have generated great enthusiasms in this field, especially for the twisted graphene.^{96,97} It is natural to ask what will happen for the moiré structures for 2D magnetic bilayers and polar bilayers.

Hopefully, this may be just the beginning of the era with rich physics to study and infinite opportunities to discover in near future.

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DATA AVAILABILITY

Data sharing is not applicable to this article as no new data were created or analyzed in this study.

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